



40V COMPLEMENTARY NPN-PNP SMALL SIGNAL TRANSISTOR IN SOT363

Features

- Complementary Pair One 3904-Type NPN One 3906-Type PNP
- Ultra-Small Surface Mount Package
- **Epitaxial Planar Die Construction**
- Ideal for Low Power Amplification and Switching
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

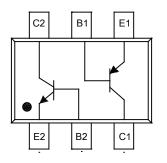
SOT363



Top View

Mechanical Data

- Case: SOT363
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Finish. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.006 grams (approximate)



E1, B1, C1 = PNP 3906 E2, B2, C2 = NPN 3904

July 2014

Device Schematic and Pinout Top View

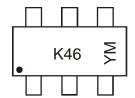
Ordering Information (Note 4)

| Product | Compliance | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|---------------|------------|---------|--------------------|-----------------|-------------------|
| MMDT3946-7-F | AEC-Q101 | K46 | 7 | 8 | 3,000 |
| MMDT3946-7R-F | AEC-Q101 | K46 | 7 | 8 | 3,000 |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



K46 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: A = 2013)M = Month (ex: 9 = September)

Date Code Key

| Year | 2010 | | 2011 | 2012 | | 2013 | 2014 | | 2015 | 2016 | | 2017 |
|-------|------|-----|------|------|-----|------|------|-----|------|------|-----|------|
| Code | X | | Υ | Z | | Α | В | | С | D | | E |
| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 0 | N | D |



Absolute Maximum Ratings, NPN 3904 (@T_A = +25°C unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|---------------------------|------------------|-------|------|
| Collector-Base Voltage | V _{CBO} | 60 | V |
| Collector-Emitter Voltage | V _{CEO} | 40 | V |
| Emitter-Base Voltage | V _{EBO} | 6.0 | V |
| Collector Current | Ic | 200 | mA |

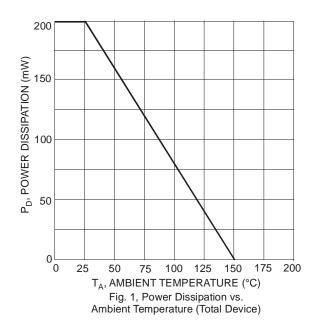
Absolute Maximum Ratings, PNP 3906 (@T_A = +25°C unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|---------------------------|------------------|-------|------|
| Collector-Base Voltage | V_{CBO} | -40 | V |
| Collector-Emitter Voltage | V _{CEO} | -40 | V |
| Emitter-Base Voltage | V _{EBO} | -5.0 | V |
| Collector Current | I _C | -200 | mA |

Thermal Characteristics, Total Device (@T_A = +25°C unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|--|-----------------------------------|-------------|------|
| Power Dissipation (Note 5) | P_D | 200 | mW |
| Thermal Resistance, Junction to Ambient Air (Note 5) | $R_{	hetaJA}$ | 625 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C |

Notes: 5. For a device mounted on minimum recommended pad layout that is on a single-sided 0.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.





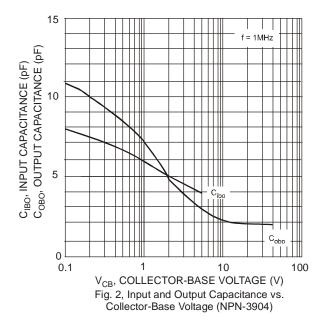
Electrical Characteristics, NPN 3904 (@T_A = +25°C unless otherwise specified.)

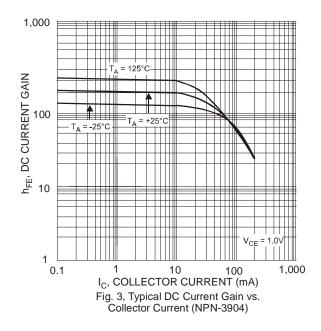
| Characteristic | Symbol | Min | Max | Unit | Test Condition |
|---------------------------------------|----------------------|-----------------------------|-----------------|--------------------|--|
| OFF CHARACTERISTICS (Note 6) | | | | | |
| Collector-Base Breakdown Voltage | BV _{CBO} | 60 | _ | V | $I_C = 10\mu A, I_E = 0$ |
| Collector-Emitter Breakdown Voltage | BV _{CEO} | 40 | _ | V | $I_C = 1.0 \text{mA}, I_B = 0$ |
| Emitter-Base Breakdown Voltage | BV _{EBO} | 5.0 | 6.0 | V | $I_E = 10\mu A, I_C = 0$ |
| Collector Cutoff Current | I _{CEX} | _ | 50 | nA | V _{CE} = 30V, V _{EB(OFF)} = 3.0V |
| Base Cutoff Current | I _{BL} | | 50 | nA | $V_{CE} = 30V, V_{EB(OFF)} = 3.0V$ |
| ON CHARACTERISTICS (Note 6) | | | | | |
| Static Forward Current Transfer Ratio | h _{FE} | 40 70 100 60 30 | 300 | _ | $\begin{split} I_{C} &= 100 \mu A, \ V_{CE} = 1.0 V \\ I_{C} &= 1.0 m A, \ V_{CE} = 1.0 V \\ I_{C} &= 10 m A, \ V_{CE} = 1.0 V \\ I_{C} &= 50 m A, \ V_{CE} = 1.0 V \\ I_{C} &= 100 m A, \ V_{CE} = 1.0 V \end{split}$ |
| Collector-Emitter Saturation Voltage | V _{CE(SAT)} | | 0.20 0.30 | V | $I_C = 10$ mA, $I_B = 1.0$ mA $I_C = 50$ mA, $I_B = 5.0$ mA |
| Base-Emitter Saturation Voltage | V _{BE(SAT)} | 0.65 | 0.85 0.95 | V | $I_C = 10$ mA, $I_B = 1.0$ mA $I_C = 50$ mA, $I_B = 5.0$ mA |
| SMALL SIGNAL CHARACTERISTICS | | | | | |
| Output Capacitance | C _{obo} | | 4.0 | pF | $V_{CB} = 5.0V$, $f = 1.0MHz$, $I_E = 0$ |
| Input Capacitance | C _{ibo} | _ | 8.0 | pF | $V_{EB} = 0.5V, f = 1.0MHz, I_{C} = 0$ |
| Input Impedance | h _{ie} | 1.0 | 10 | kΩ | |
| Voltage Feedback Ratio | h _{re} | 0.5 | 8.0 | x 10 ⁻⁴ | $V_{CE} = 10V, I_{C} = 1.0mA,$ |
| Small Signal Current Gain | h _{fe} | 100 | 400 | — | f = 1.0kHz |
| Output Admittance | h _{oe} | 1.0 | 40 | μS | |
| Current Gain-Bandwidth Product | f⊤ | 300 | | MHz | $V_{CE} = 20V$, $I_C = 20mA$, $f = 100MHz$ |
| Noise Figure | NF | | 5.0 | dB | $V_{CE} = 5.0V, I_{C} = 100\mu A,$ $R_{S} = 1.0k\Omega, f = 1.0kHz$ |
| SWITCHING CHARACTERISTICS | | | | | |
| Delay Time | t _d | _ | 35 | ns | $V_{CC} = 3.0V, I_C = 10mA,$ |
| Rise Time | t _r | _ | 35 | ns | $V_{BE(off)} = -0.5V, I_{B1} = 1.0mA$ |
| Storage Time | ts | _ | 200 | ns | V _{CC} = 3.0V, I _C = 10mA, |
| Fall Time | t _f | _ | 50 | ns | $I_{B1} = I_{B2} = 1.0 \text{mA}$ |

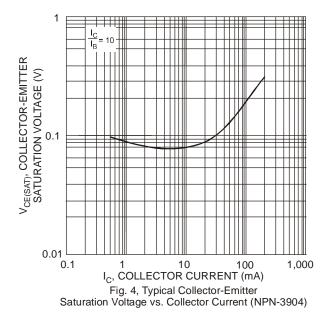
Notes: 6. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%

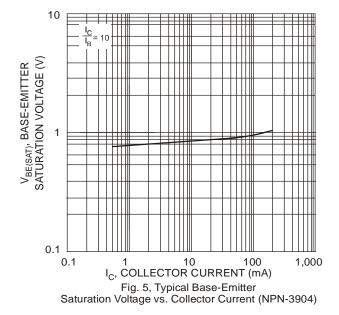


Typical Electrical Characteristics, NPN 3904 (@T_A = +25°C unless otherwise specified.)











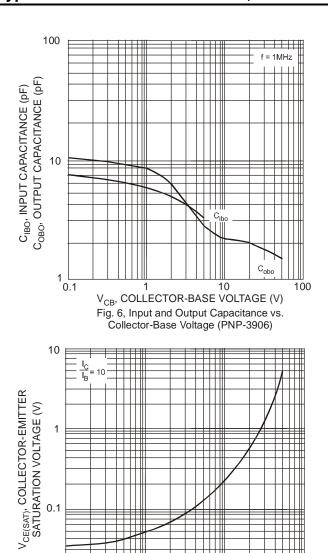
Electrical Characteristics, PNP 3906 (@T_A = +25°C unless otherwise specified.)

| Characteristic | Symbol | Min | Max | Unit | Test Condition |
|---------------------------------------|----------------------|-----------------------------|----------------|--------------------|--|
| OFF CHARACTERISTICS (Note 6) | | | | | |
| Collector-Base Breakdown Voltage | BV _{CBO} | -40 | _ | V | $I_C = -10\mu A, I_E = 0$ |
| Collector-Emitter Breakdown Voltage | BV _{CEO} | -40 | _ | V | $I_C = -1.0 \text{mA}, I_B = 0$ |
| Emitter-Base Breakdown Voltage | BV _{EBO} | -5.0 | _ | V | $I_E = -10\mu A, I_C = 0$ |
| Collector Cutoff Current | I _{CEX} | _ | -50 | nA | $V_{CE} = -30V, V_{EB(OFF)} = -3.0V$ |
| Base Cutoff Current | I _{BL} | _ | -50 | nA | $V_{CE} = -30V, V_{EB(OFF)} = -3.0V$ |
| ON CHARACTERISTICS (Note 6) | | | | | |
| Static Forward Current Transfer Ratio | h _{FE} | 60 80 100 60 30 | 300 — — | _ | $\begin{split} I_C &= -100 \mu A, \ V_{CE} = -1.0 V \\ I_C &= -1.0 m A, \ V_{CE} = -1.0 V \\ I_C &= -10 m A, \ V_{CE} = -1.0 V \\ I_C &= -50 m A, \ V_{CE} = -1.0 V \\ I_C &= -100 m A, \ V_{CE} = -1.0 V \end{split}$ |
| Collector-Emitter Saturation Voltage | V _{CE(SAT)} | _ | -0.25 -0.40 | V | $I_C = -10$ mA, $I_B = -1.0$ mA $I_C = -50$ mA, $I_B = -5.0$ mA |
| Base-Emitter Saturation Voltage | V _{BE(SAT)} | -0.65 — | -0.85 -0.95 | V | $I_C = -10\text{mA}, I_B = -1.0\text{mA}$ $I_C = -50\text{mA}, I_B = -5.0\text{mA}$ |
| SMALL SIGNAL CHARACTERISTICS | | | | | |
| Output Capacitance | C _{obo} | _ | 4.5 | pF | $V_{CB} = -5.0V$, $f = 1.0MHz$, $I_E = 0$ |
| Input Capacitance | C _{ibo} | _ | 10 | pF | $V_{EB} = -0.5V$, $f = 1.0MHz$, $I_C = 0$ |
| Input Impedance | h _{ie} | 2.0 | 12 | kΩ | |
| Voltage Feedback Ratio | h _{re} | 0.1 | 10 | x 10 ⁻⁴ | $V_{CE} = 10V, I_{C} = 1.0mA,$ |
| Small Signal Current Gain | h _{fe} | 100 | 400 | | f = 1.0kHz |
| Output Admittance | h _{oe} | 3.0 | 60 | μS | |
| Current Gain-Bandwidth Product | f⊤ | 250 | _ | MHz | V _{CE} = -20V, I _C = -10mA, f = 100MHz |
| Noise Figure | NF | _ | 4.0 | dB | $V_{CE} = -5.0V, I_{C} = -100\mu A,$ $R_{S} = 1.0k\Omega, f = 1.0kHz$ |
| SWITCHING CHARACTERISTICS | | | | | |
| Delay Time | t _d | _ | 35 | ns | $V_{CC} = -3.0V, I_{C} = -10mA,$ |
| Rise Time | t _r | _ | 35 | ns | $V_{BE(off)} = 0.5V, I_{B1} = -1.0mA$ |
| Storage Time | ts | _ | 225 | ns | $V_{CC} = -3.0V, I_{C} = -10mA,$ |
| Fall Time | t _f | | 75 | ns | $I_{B1} = I_{B2} = -1.0 \text{mA}$ |



0.01

Typical Electrical Characteristics, PNP 3906 (@T_A = +25°C unless otherwise specified.)



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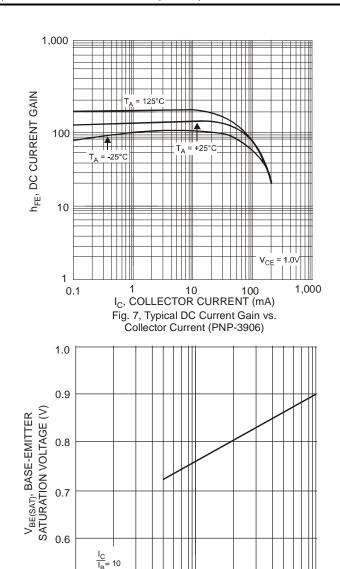
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I_C, COLLECTOR CURRENT (mA)

Fig. 8, Typical Collector-Emitter Saturation Voltage

vs. Collector Current (PNP-3906)

1,000



100

July 2014

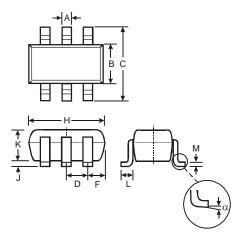
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0.5



Package Outline Dimensions

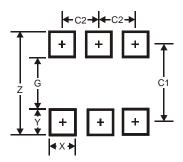
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



| | SOT363 | | | | | | | |
|-----|----------------------|------|-------|--|--|--|--|--|
| Dim | Min | Max | Тур | | | | | |
| Α | 0.10 | 0.30 | 0.25 | | | | | |
| В | 1.15 | 1.35 | 1.30 | | | | | |
| С | 2.00 | 2.20 | 2.10 | | | | | |
| D | 0.65 Typ | | | | | | | |
| F | 0.40 | 0.45 | 0.425 | | | | | |
| Н | 1.80 | 2.20 | 2.15 | | | | | |
| J | 0 | 0.10 | 0.05 | | | | | |
| K | 0.90 | 1.00 | 1.00 | | | | | |
| L | 0.25 | 0.40 | 0.30 | | | | | |
| М | 0.10 | 0.22 | 0.11 | | | | | |
| α | 0° | 8° | - | | | | | |
| All | All Dimensions in mm | | | | | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| Z | 2.5 |
| G | 1.3 |
| Х | 0.42 |
| Υ | 0.6 |
| C1 | 1.9 |
| C2 | 0.65 |



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 - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
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